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Correction: Individual single-crystal nanowires as electrodes for organic single-crystal nanodevices

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Correction for 'Individual single-crystal nanowires as electrodes for organic single-crystal nanodevices' by Guorui Wang *et al.*, *J. Mater. Chem. C*, 2015, DOI: 10.1039/c5tc01920f.

The equation for calculating mobility in the saturated regime (I_{SD}) in the last sentence of the experimental section on the second page of this article contained some errors. The correct version is as follows:

$$I_{SD} = \frac{W}{2L} \cdot \mu C_i (V_G - V_T)^2$$

where W is the channel width, L is the channel length, C_i is the dielectric unit area capacitance, μ is field-effect mobility, V_G is gate voltage, and V_T is the threshold voltage.

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

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